ZXTN25060BZQ

60V NPN MEDIUM POWER TRANSISTOR IN SOT89

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- BV_{CEX} > 150V
- BV_{CEO} > 60V
- BV_{ECO} > 6V
- I_C = 5A Continuous Collector Current
- $V_{CE(sat)}$ < 70mV @ 1A
- $R_{CE(sat)}$ = 48mΩ for a Low Equivalent On-Resistance
- Very Low Saturation Voltages
- Excellent hFE Characteristics
- 6V Reverse Blocking Capability
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

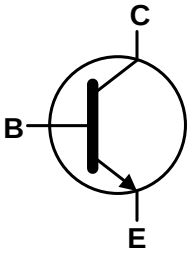
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.055 grams (Approximate)

Applications

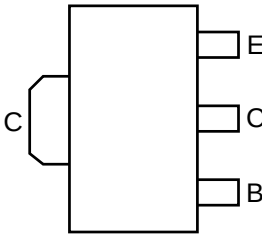
- Motor Driving (including DC fans)
- Solenoid, Relay and Actuator Drivers
- DC-DC Modules
- Power Switches
- MOSFET Gate Drivers

SOT89

Top View



Equivalent Circuit



Top View
Pin-Out

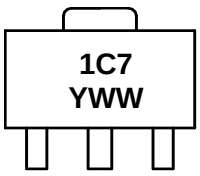
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25060BZQTA	Automotive	1C7	7	12mm	1,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.
5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT89



1C7= Product Type Marking Code
YWW = Date Code Marking
Y = Last Digit of Year (ex: 5 = 2015)
WW = Week Code (01 ~ 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	150	V
Collector-Emitter Voltage (Forward Blocking)	V_{CEX}	150	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Collector Voltage (Reverse Blocking)	V_{ECO}	6	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	5	A
Base Current	I_B	1	A
Peak Pulse Current	I_{CM}	10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

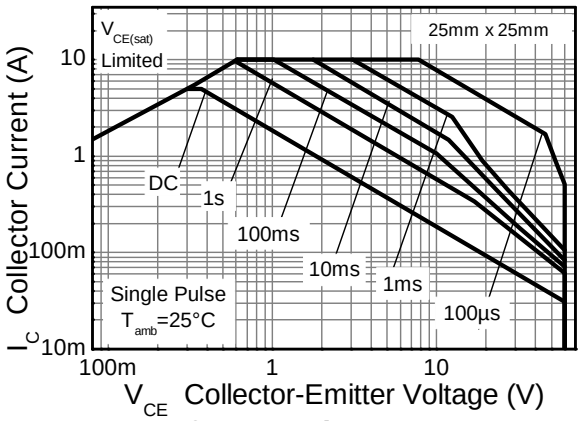
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	P_D	1.1	W
	(Note 7)		1.8	
	(Note 8)		2.4	
	(Note 9)		4.46	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{\theta JA}$	117	°C/W
	(Note 7)		68	
	(Note 8)		51	
	(Note 9)		28	
Thermal Resistance, Junction to Lead	(Note 10)	$R_{\theta JL}$	8	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 11)

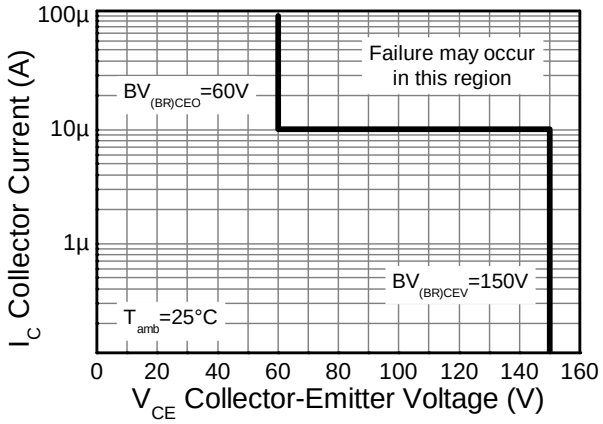
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
8. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
9. Same as Note 7 measured at t<5 seconds.
10. Thermal resistance from junction to solder-point (on the exposed collector pad).
11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

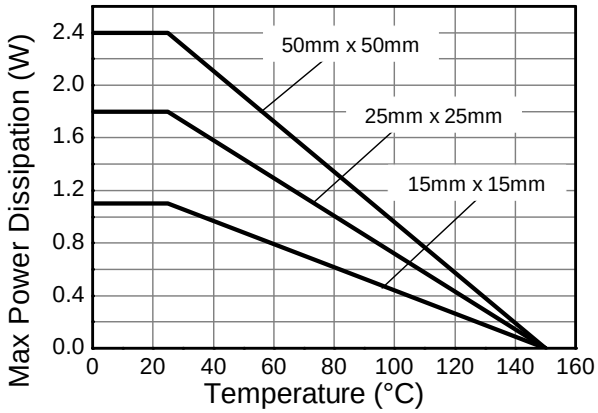
Thermal Characteristics and Derating Information



Safe Operating Area

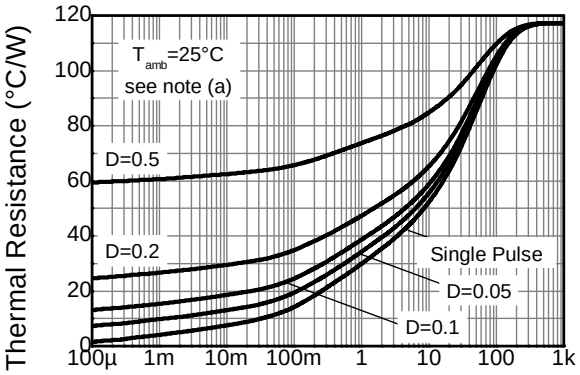


Safe Operating Area

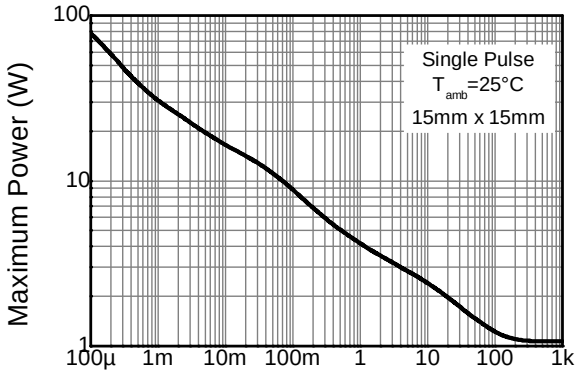


Derating Curve

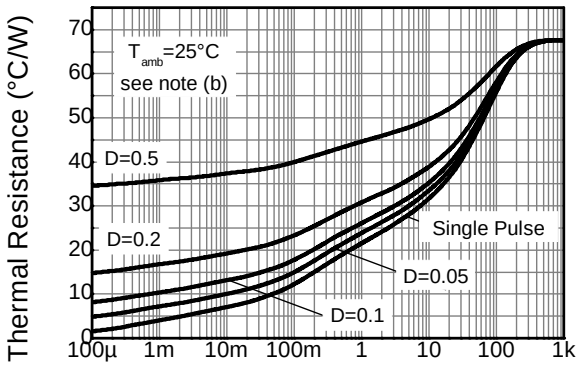
Thermal Characteristics and Derating Information (continued)



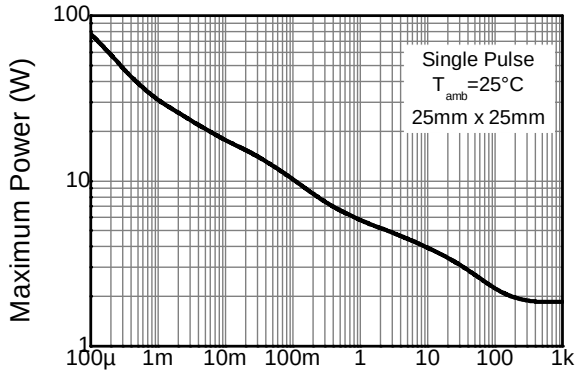
Transient Thermal Impedance



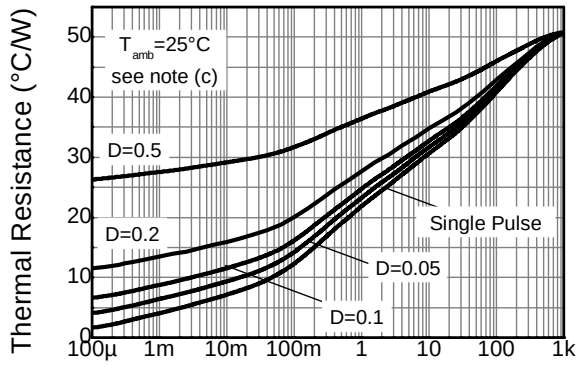
Pulse Power Dissipation



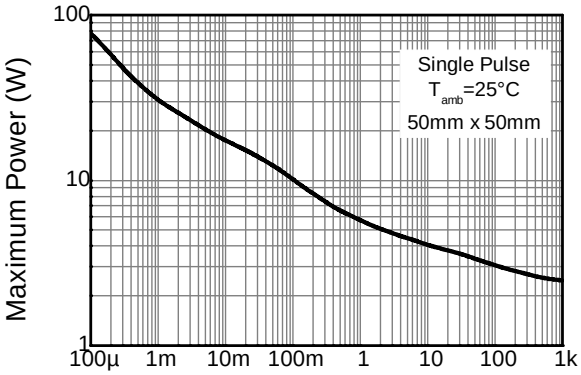
Transient Thermal Impedance



Pulse Power Dissipation



Transient Thermal Impedance



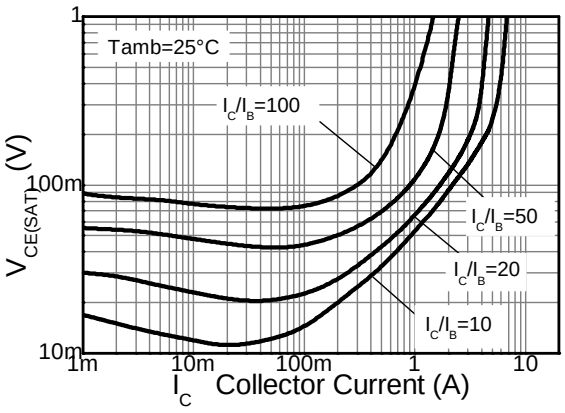
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

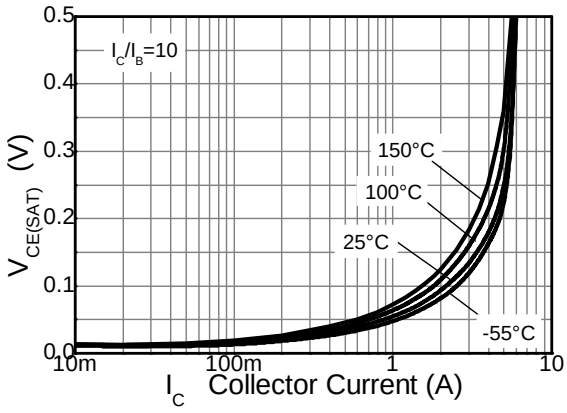
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	150	190	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Forward Blocking)	BV_{CEX}	150	190	—	V	I_C = 100µA, R_{BE} ≤1kΩ or -1V < V_{BE} <0.25V
Collector-Emitter Breakdown Voltage (Note 12)	BV_{CEO}	60	80	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.0	—	V	I_E = 100µA
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV_{ECX}	6	8	—	V	I_E = 100µA, R_{BC} ≤1kΩ or <0.25V > V_{BC} >0.25V
Emitter-Collector Breakdown Voltage (Base Open)	BV_{ECO}	6	7	—	V	I_E = 100µA
Collector-Base Cutoff Current	I_{CBO}	—	<1	50 20	nA µA	V_{CB} = 120V V_{CB} = 120V, T_A = +100°C
Collector-Emitter Cutoff Current	I_{CEX}	—	—	100	nA	V_{CE} = 120V, R_{BE} ≤1kΩ or -1V < V_{BE} <0.25V
Emitter-Base Cutoff Current	I_{EBO}	—	<1	50	nA	V_{EB} = 5.6V
Collector-Emitter Saturation Voltage (Note 12)	$V_{CE(sat)}$	—	55 70 185 240	70 90 230 305	mV	I_C = 1A, I_B = 100mA I_C = 1A, I_B = 50mA I_C = 4A, I_B = 400mA I_C = 5A, I_B = 500mA
Base-Emitter Saturation Voltage (Note 12)	$V_{BE(sat)}$	—	1,020	1,100	mV	I_C = 5A, I_B = 500mA
Base-Emitter Turn-On Voltage (Note 12)	$V_{BE(on)}$	—	960	1,050	mV	I_C = 5A, V_{CE} = 2V
DC Current Gain (Note 12)	h_{FE}	100 90 45 —	200 180 90 20	300 — — —	—	I_C = 10mA, V_{CE} = 2V I_C = 1A, V_{CE} = 2V I_C = 2A, V_{CE} = 50V I_C = 5A, V_{CE} = 5V
Transitional Frequency	f_T	—	185	—	MHz	I_C = 100mA, V_{CE} = 5V f=100MHz
Output Capacitance	C_{obo}	—	11.5	20	pF	V_{CB}= 10V, f=1MHz
Delay Time	t_d	—	16	—	ns	V_{CC} = 10V, I_{CC} = 500mA I_{B1} = - I_{B2} = 50mA
Rise Time	t_r	—	15	—	ns	
Storage Time	t_s	—	509	—	ns	
Fall Time	t_f	—	57	—	ns	

Note: 12. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

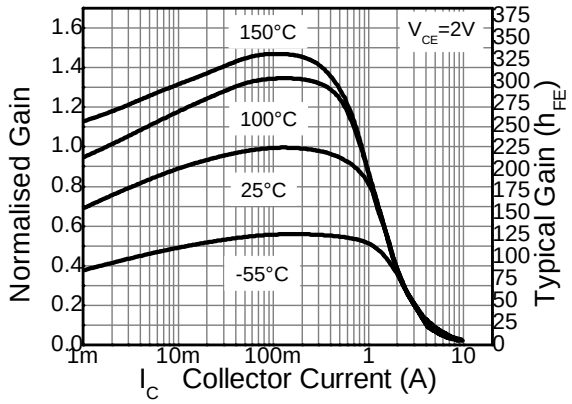
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



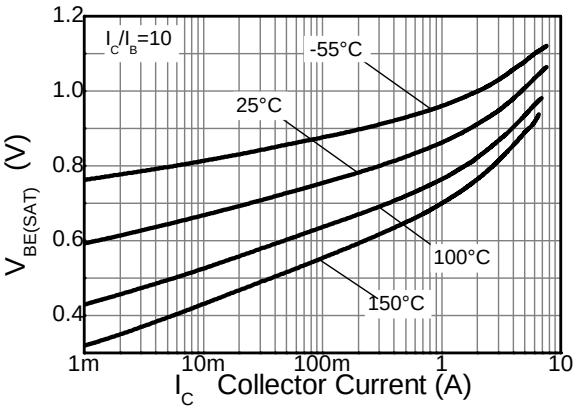
$V_{CE(SAT)}$ v I_C



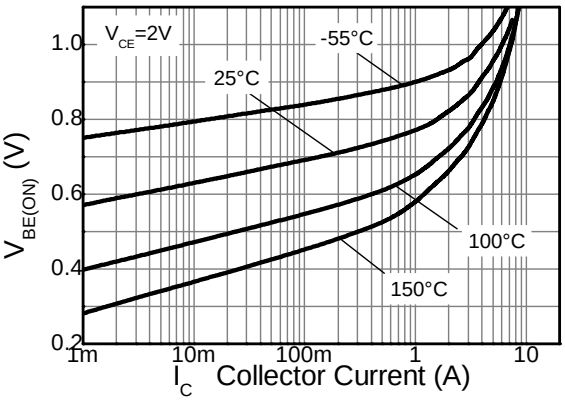
$V_{CE(SAT)}$ v I_C



h_{FE} v I_C



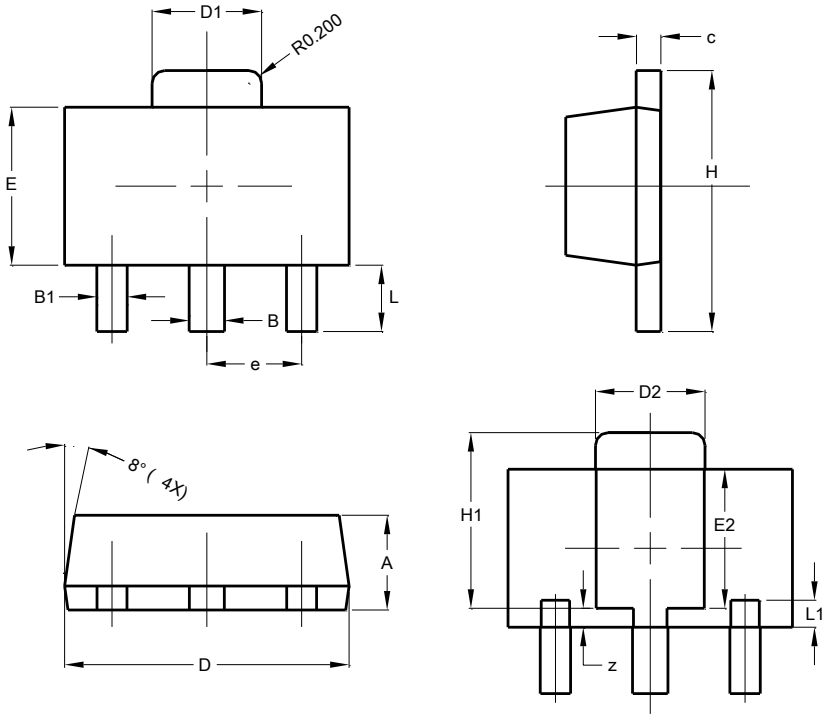
$V_{BE(SAT)}$ v I_C



$V_{BE(ON)}$ v I_C

Package Outline Dimensions

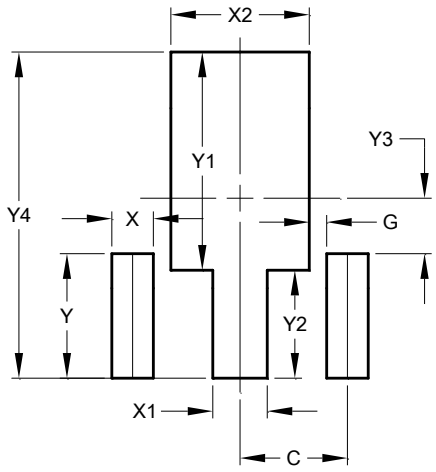
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT89			
Dim	**Min**	**Max**	**Typ**
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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